

As a consequence, anti-ferroelectric dielectric materials have attracted increasing attention due to their excellent electric properties for high energy storage capacitors and pulsed power ...

This work demonstrates that high entropy is an effective but convenient strategy to design new high-performance dielectrics, promoting the development of advanced pulse power ...

Ferroelectric (FE) hafnium oxides (HfO 2), such as hafnium zirconium oxide (HZO), are promising thin film ferroelectric materials for nonvolatile memory applications, which feature fast speed, 1-9 long retention, 1,10 high endurance, 10-12 and a CMOS compatible fabrication process. 13,14 The time response of polarization switching ...

a Polarization P vs. electric field E a characteristics of a TiN/ZrO 2 (10 nm)/TiN capacitor measured using a standard ferroelectric tester at 1 kHz. b Low magnification high angle annular dark ...

The newly developed capacitor exhibits a wide temperature usage range of -60 to 120 °C, with an energy-density variation of less than 10%, and satisfactory cycling reliability, with degradation of more than 8% over 106 ...

Comprehensive large-signal performance analysis of ceramic capacitors for power pulsation buffers. 2016 IEEE 17th Work. Control Model. Power Electron. COMPEL 2016 (2016), 10.1109/COMPEL.2016. ... Stabilization of anti-ferroelectric Pbcm phase over ferroelectric P2 1 ma phase in intermittent ferroelectric NaNbO 3 by incorporating ...

Chen et al. attempted to fabricate slim-loop ferroelectric ceramics that were focussed for high-power pulse capacitor applications. The researchers systematically investigated the effect of partial replacement of A and B site ions in Pb(Zr,Sn,Ti)O 3 with Ba, La and Nb respectively.

Up to now, such works are still limited, and mainly focused on Pb(Zr,Sn,Ti)O 3 systems and concerned about pulse power applications. [125, 128, [149][150][151][152][153][154] A typical charge ...

The scalability of neuromorphic devices depends on the dismissal of capacitors and additional circuits. ... the anti-ferroelectric neuron exhibits low energy consumption (37 fJ/spike), high ...

Temperature-Dependent Stability of Energy Storage Properties of Pb0.97La0.02 (Zr0.58 Sn0.335Ti0.085)O3 Antiferroelectric Ceramics for Pulse Power Capacitors June 2015 Applied Physics Letters 106(26)

On this basis, an ultrahigh output power density up to 2.2 × 10 9 W kg -1 (GW kg -1) with an output voltage up to 9.8 kV mm -1 is achieved in shock wave ...



Anti-ferroelectric pulse power capacitor

Dielectric ceramic capacitors, with the advantages of high power density, fast charge- discharge capability, excellent fatigue endurance, and good high temperature stability, have been acknowledged to be promising candidates for solid-state pulse power systems. This review investigates the energy storage performances of linear dielectric, relaxor ...

Charge-discharge properties of an La-modified Pb(Zr,Sn,Ti)O3 (PLZST) antiferroelectric (AFE) ceramics capacitor were investigated by directly measuring its hysteresis loops and pulse discharge current-time curves under different electric fields. Large increments in polarization and discharge current were observed when the electric ...

Ferroelectric (FE) materials are promising for applications in advanced high-power density systems/energy storage and conversion devices. However, the power density of ceramic components is limited by the electrode area and breakdown strength of bulk ceramic, while the multilayer structure is effective in enhancing Journal of Materials ...

Energy storage capacitors occupy a large proportion in the pulse power equipment, and they play an important role nowadays. In recent years, anti-ferroelectric materials have attracted increasing attention of researchers due to their high energy storage density. Compared with the lead-free anti-ferroelectric materials, PbZrO3 (PZ)-based ...

As the fundamental energy storage components in electronic systems, dielectric capacitors with high power densities were demanded. In this work, the anti-ferroelectric Pb0.89La0.06Sr0.05(Zr0.95Ti0 ...

As the fundamental energy storage components in electronic systems, dielectric capacitors with high power densities were demanded. In this work, the anti-ferroelectric Pb 0.89 La 0.06 Sr 0.05 (Zr 0.95 Ti 0.05)O 3 (PLSZT) ceramics and thin film capacitor were successfully fabricated by a solid-state reaction route and pulsed laser deposition ...

Antiferroelectric materials feature electric-field-induced phase transitions followed by a large polarization change characterized by double polarization hysteresis ...

Anti-ferroelectric thin-film capacitors with high energy-storage densities, low energy losses, and fast discharge times. ACS Appl. Mater. Interfaces, ... (Zr 0.58 Sn 0.335 Ti 0.085)O 3 anti-ferroelectric ceramics for pulse power capacitors. Appl. Phys. Lett., 106 (2015), Article 262901. View in Scopus Google Scholar

This is followed by a general description of anti-ferroelectricity and important anti-ferroelectric materials. The remainder of the paper is divided into two subsections, the first of which presents various physical routes for enhancing the energy storage density while the latter section describes chemical routes for enhanced storage ...

Pulse power technology refers to the fascinating field of electrical physics where smaller amounts of energy are carefully stored over longer durations and then, ... emerge as the quintessential choice for pulse capacitors



Anti-ferroelectric pulse power capacitor

[[6], [7] ... Anti-ferroelectric ceramics for high energy density capacitors. Materials, 8 (12) (2015) ...

The polarization of (Pb0.94La0.04)[(Zr0.7Sn0.3)0.87Ti0.13]O3 antiferroelectric (AFE) ceramics under unipolar pulse electric field was studied, and the transient hysteresis loop was achieved.

Energy storage capacitors occupy a large proportion in the pulse power equipment, and they play an important role nowadays. In recent years, anti-ferroelectric materials have attracted ...

The newly developed capacitor exhibits a wide temperature usage range of -60 to 120 °C, with an energy-density variation of less than 10%, and satisfactory cycling reliability, with degradation of more than 8% over 106 cycles demonstrate that the NBT-0.45SBT multilayer ceramic is a promising candidate for high-power energy storage applications.

For purpose of further studying the discharge behavior of antiferroelectric materials for pulse capacitors, (Pb 0·98 La 0.02)(Zr 0·45 Sn 0.55) 0.995 O 3 ... Anti-ferroelectric ceramics for high energy density capacitors. Materials, 8 (2015), ... O3 antiferroelectric ceramics for pulse power capacitors. Appl. Phys. Lett., 106 ...

The effect of internal clamping at a microscopic level due to glass incorporation, in anti-ferroelectric material for (a) pure ceramic; (b) ceramic with glass incorporation; (c) pure ceramic ...

The energy in pulse capacitors need to discharge rapidly to obtain high peak power. However, the discharge energy density of antiferroelectric (AFE) dielectrics for pulse capacitors is traditionally evaluated by hysteresis loop (defined as quasi-static method). To verify whether the quasi-static method is suitable for pulse applications, AFE ceramics ...

Relaxor antiferroelectric (AFE) ceramic capacitors have drawn growing attention in future advanced pulsed power devices for their superior energy storage performance. However, state of the art dielectric ...

Ferroelectric (FE) materials are promising for applications in advanced high-power density systems/energy storage and conversion devices. However, the power density of ceramic components is limited by the electrode area and breakdown strength of bulk ceramic, while the multilayer structure is effective in enhancing the breakdown ...

Pulsed capacitors require high energy density and low loss, properties that can be realized through selection of composition. Ceramic (Pb 0.88 La 0.08)(Zr 0.91 Ti 0.09)O 3 was found to be an ideal candidate. La 3+ doping and excess PbO were used to produce relaxor antiferroelectric behavior with slim and slanted hysteresis loops to ...

By applying a voltage pulse on the NC capacitor in series with an external resistor (R-C circuit), the voltage drop across the ferroelectric is observed in the limited time range with charge Q ...



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